Asahi **KASEI**

Magnetic Solution Provider A Small Sensor Opens the Way to Future Technologies

Sensor Solution

Asahi Kasei's Hall sensors are playing an active part in your everyday world. They contribute to the high accuracy, long life, and compact designs of various systems as well as their good-looking appearance and usability. As a leading company of magnetic sensors, Asahi Kasei will continuously offer innovative sensor technologies.

ASAHI KASEI EMD Corp.

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Asahi Kasei EMD is the world leader in Hall elements. The main applications of our Hall elements are the brushless motors used in CD/DVD drives and fans. At present, we are manufacturing these elements to over 1 billion in a year. With a wide range of package variants and materials, we can address diversifying customer needs.

-Package: SOP, DIP, SIP, SON, etc.

-Material: HW, HS series (InSb) Ultra high sensitivity -HG series (GaAs) Improved temperature characteristics -HQ, HZ series (InAs): High sensitivity, improved temperature characteristics



*For further details, refer to the Hall element catalog.

	EW series			
Hall IC	EM series			
	EZ series			

Asahi Kasei EMD is manufacturing Hall ICs by utilizing highsensitivity Hall elements and our proprietary signal processing technologies. With the wide lineups varying in operation type, Operating point, and package size, our products are being used in various applications from OA equipment and electric appliances to mobile appliances. We also offer substantial design supports based on our rich experiences in the magnetic simulation and magnetic field measurement.

-Detection type: Unipolar switch, Omnipolar switch, Bipolar Latch -Package: SOP, SON, SIP

-Operating point: 1.5, 3, 6, or 10 mT depending on the type -Supply voltage: 1.8, 3, 5, 12, or 24 V depending on the type -Operating temperature: 85, 115, or 125°C depending on the type



*For further details, refer to the Hall effect IC.

Multi-chip Hall IC for pointing devices EQ-8441



Features

 2D position detection digital output: Integrates four Hall elements and one control IC into a single package.

 Integrates a 8-bit A/D converter to output serial signals corresponding to detected X/Y positions

 Low power consumption: Integrates an intermittent operation circuit, power down function

 Interruption function: No need for constant reading because this function alerts the host to any operation of the pointing device.

Block diagram (EQ-8441)



Main specifications: EQ-8441

Item	Symbol	Condition	Unit	Min	Тур.	Max.
Supply voltage	VDD		V	2.5	3.0	3.3
I/F voltage	VID		V	1.75	1.85	VDD
Current consumption	IDD1	Power down mode	μA		0.5	5
	DD2	Sensor drive	mA		3.9	6.3
	DD3	External clock mode	μA		6	19
	IDD4	Internal clock mode	μA		26	46
ADC resolution	RSL		bit		8	
Sampling cycle	SINT2	External clock mode	ms		15.63	
	SINT1	Internal clock mode	ms	6.3	10	16.4
Master clock frequency	FCLK1	External clock mode	kHz		32.77	
	FCLK2	Internal clock mode	kHz	250	400	650

Operation principle

Four Hall elements detect the magnetic field generated by a magnet. The IC reads the differences across the magnetic flux density values given by these elements, and thus determines the current position of the magnet as a set of 2D coordinate data.





Outline of APD (Sectional view)

Diagram of APD (Plane view)

X-axis	Y-axis	Detected position
HE1output=HE4output	HE2output=HE3output	Magnet is at center
HE1output>HE4output	HE2output>HE3output	Magnet is at upper right

Hall sensor for close position sensing

Features

- Simple configuration made up of a magnet and a Hall element
- Resistant to dirt and dust
- Allows detection with accuracy up to μ m order
- Wide range of line ups
- Allows compact design
- No time decay in output
- High quality design support, magnetic field measurement, and magnetic simulation based on our rich experiences

Major applications (actual implementations)

- Position detection for lens and CCD in DSC, DVC antishake systems
- Position detection for autofocus lens and zoom lens



Typical designs for close position Sensing



We will propose an optimum design based on your requests (stroke, accuracy).

(Note) The accuracy represents displacement from a linear curve.

AE-8001 EM-3241 (under development) Rotation angle sensor

Features - Rotation angle sensor using a Hall element

- Detects the rotation angle of a radially magnetized disc magnet as an absolute angle

AE-8001 EM-3241 (under development) - Consists of three chips of two Hall elements and one - Integrates a Hall element and a processing IC into a processing IC single package - Hall elements in use are SMT (HZ-116C) and - Ultra-compact 6-pin package: 3.6 x 3.0 x t0.95 mm SIP (HZ-312C) - Resolution: 9 bits (10-bit version is being Resolution: 12 bits developed.) Output format - Output format Ratiometric analog output Ratiometric analog output 111111 12-bit digital output N - Supply voltage: 3 to 5 V - Integrates non-volatile memories, - Operating temperature range: allowing user programming -30 to 85℃ - Supply voltage: 5 V - Operating temperature range: -40 to 125℃ EQ-40L,EG-70L,EG-40L (under development) **Linear Hall IC EQ-70L**

Features - Integrates a high-sensitivity Hall element and a processing IC into a single package



- single package - Driven with two-phase half wave
 - Supply voltage: 3.5 to 15 V

 - Motor current: 500 mA
 - With lock monitor terminal
 - EM-300: Tachometer signal output
 - EM-301: Alarm signal output

OUT1 Vdd OUT2 EM-300 Synchronized output TEST LA Vss

CQ-120E,130E **Current sensor**

Features

CQ-120E

- Ultra-compact open type current sensor
- Compliant to IEC standard for insulation
- Quick response: 5µs

CQ-130E

- Rated current: 20 A - Supply voltage: 5 V
- Rated current: 30 A - Supply voltage: 5 V



Semiconductor magnetoresistive element

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Features

- Detects a rotation angle with high accuracy by the combination of a
- semiconductor magnetoresistive element and a bias magnet
- Improved temperature characteristics of output voltage - Detects the phases A/B
- Two versions available, m = 0.2 and m = 0.4

MS-0040,0020 (under development)



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